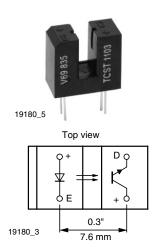


Vishay Semiconductors

### **Transmissive Optical Sensor with Phototransistor Output**

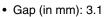


#### **DESCRIPTION**

The TCST1103, TCST1202, and TCST1300 are transmissive sensors that include an infrared emitter and phototransistor, located face-to-face on the optical axes in a leaded package which blocks visible light. These part numbers include options for aperture width.

#### **FEATURES**

- Package type: leaded
- Detector type: phototransistor
- Dimensions (L x W x H in mm): 11.9 x 6.3 x 10.8



• Typical output current under test:  $I_C = 4 \text{ mA}$  (TCST1103)



- Typical output current under test: I<sub>C</sub> = 2 mA (TCST1202)
- Typical output current under test: I<sub>C</sub> = 0.5 mA (TCST1300)
- · Daylight blocking filter
- Emitter wavelength: 950 nm
- Lead (Pb)-free soldering released
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### **APPLICATIONS**

- · Optical switch
- Photo interrupter
- Counter
- Encoder

PRODUCT SUMMARY							
PART NUMBER	BER GAP WIDTH (mm)		TYPICAL OUTPUT CURRENT UNDER TEST (1) (mA)	DAYLIGHT BLOCKING FILTER INTEGRATED			
TCST1103	3.1	1	4	Yes			
TCST1202	3.1	0.5	2	Yes			
TCST1300	3.1	0.25	0.5	Yes			

#### Note

<sup>(1)</sup> Conditions like in table basic characteristics/coupler

ORDERING INFORMATION						
ORDERING CODE	PACKAGING	VOLUME (1)	REMARKS			
TCST1103	Tube	MOQ: 1020 pcs, 85 pcs/tube	Without mounting flange			
TCST1202	Tube	MOQ: 1020 pcs, 85 pcs/tube	Without mounting flange			
TCST1300	Tube	MOQ: 1020 pcs, 85 pcs/tube	Without mounting flange			

#### Note

<sup>(1)</sup> MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (1)							
PARAMETER	TEST CONDITION	VALUE	UNIT				
COUPLER							
Total power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>tot</sub>	250	mW			
Ambient temperature range		T <sub>amb</sub>	- 55 to + 85	°C			
Storage temperature range		T <sub>stg</sub>	- 55 to + 100	°C			
Soldering temperature	Distance to package: 2 mm; t ≤ 5 s	T <sub>sd</sub>	260	°C			

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### TCST1103, TCST1202, TCST1300

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ABSOLUTE MAXIMUM RATINGS (1)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT (EMITTER)								
Reverse voltage		$V_{R}$	6	V				
Forward current		I <sub>F</sub>	60	mA				
Forward surge current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	3	A				
Power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>V</sub>	100	mW				
Junction temperature		Tj	100	°C				
OUTPUT (DETECTOR)								
Collector emitter voltage		V <sub>CEO</sub>	70	V				
Emitter collector voltage		V <sub>ECO</sub>	7	V				
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	200	mA				
Power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>V</sub>	150	mW				
Junction temperature		T <sub>j</sub>	100	°C				

#### Note

#### **ABSOLUTE MAXIMUM RATINGS**

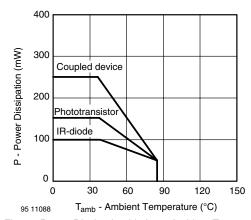


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (1)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
COUPLER							
Current transfer ratio	V <sub>CE</sub> = 5 V, I <sub>F</sub> = 20 mA	TCST1103	CTR	10	20		%
		TCST1202	CTR	5	10		%
		TCST1300	CTR	1.25	2.5		%
	V <sub>CE</sub> = 5 V, I <sub>F</sub> = 20 mA	TCST1103	I <sub>C</sub>	2	4		mA
Collector current		TCST1202	Ic	1	2		mA
		TCST1300	I <sub>C</sub>	0.25	0.5		mA
	$I_F = 20 \text{ mA}, I_C = 1 \text{ mA}$	TCST1103	V <sub>CEsat</sub>			0.4	V
Collector emitter saturation voltage	$I_F = 20 \text{ mA}, I_C = 0.5 \text{ mA}$	TCST1202	V <sub>CEsat</sub>			0.4	V
	$I_F = 20 \text{ mA}, I_C = 0.1 \text{ mA}$	TCST1300	V <sub>CEsat</sub>			0.4	V
Resolution, path of the shutter crossing the radiant sensitive zone	I <sub>Crel</sub> = 10 % to 90 %	TCST1103	s		0.6		mm
		TCST1202	s		0.4		mm
		TCST1300	s		0.2		mm

 $<sup>^{(1)}</sup>$  T<sub>amb</sub> = 25 °C, unless otherwise specified



## Transmissive Optical Sensor with Phototransistor Output

## Vishay Semiconductors

BASIC CHARACTERISTICS (1)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT (EMITTER)							
Forward voltage	I <sub>F</sub> = 60 mA		$V_{F}$		1.25	1.6	٧
Junction capacitance	$V_R = 0 V, f = 1 MHz$		C <sub>j</sub>		50		pF
OUTPUT (DETECTOR)							
Collector emitter voltage	I <sub>C</sub> = 1 mA		$V_{CEO}$	70			V
Emitter collector voltage	I <sub>E</sub> = 10 μA		V <sub>ECO</sub>	7			V
Collector dark current	$V_{CE} = 25 \text{ V}, I_F = 0 \text{ A}, E = 0 \text{ lx}$		I <sub>CEO</sub>			100	nA
SWITCHING CHARACTERISTICS							
Turn-on time	$I_C = 2 \text{ mA}, V_S = 5 \text{ V},$ $R_L = 100 \Omega \text{ (see figure 2)}$		t <sub>on</sub>		10		μs
Turn-off time	$I_C = 2 \text{ mA}, V_S = 5 \text{ V},$ $R_L = 100 \Omega \text{ (see figure 2)}$		t <sub>off</sub>		8		μs

#### Note

 $^{(1)}$  T<sub>amb</sub> = 25 °C, unless otherwise specified

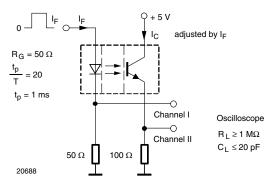


Fig. 2 - Test Circuit for ton and toff

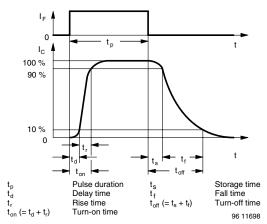


Fig. 3 - Switching Times

#### **BASIC CHARACTERISTICS**

 $T_{amb}$  = 25 °C, unless otherwise specified

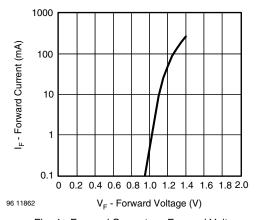


Fig. 4 - Forward Current vs. Forward Voltage

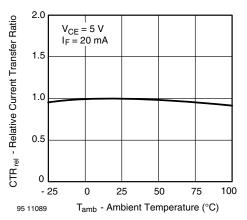


Fig. 5 - Relative Current Transfer Ratio vs. Ambient Temperature

## TCST1103, TCST1202, TCST1300

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## Transmissive Optical Sensor with Phototransistor Output



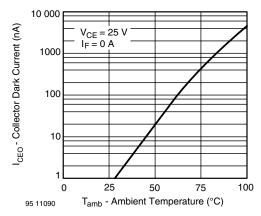


Fig. 6 - Collector Dark Current vs. Ambient Temperature

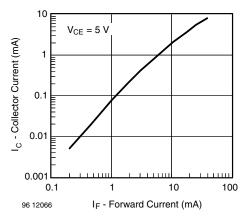


Fig. 7 - Collector Current vs. Forward Current

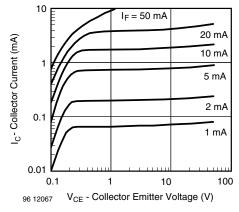


Fig. 8 - Collector Current vs. Collector Emitter Voltage

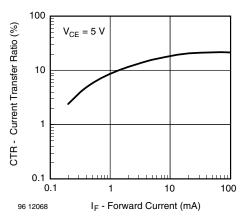


Fig. 9 - Current Transfer Ratio vs. Forward Current

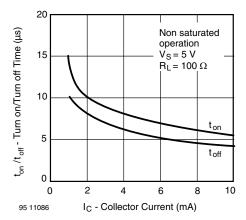


Fig. 10 - Turn-off/Turn-on Time vs. Collector Current

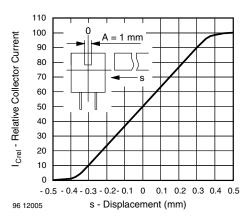


Fig. 11 - Relative Collector Current vs. Displacement



### Transmissive Optical Sensor with Phototransistor Output

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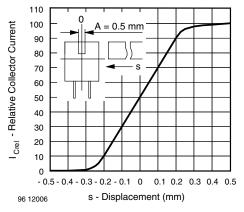


Fig. 12 - Relative Collector Current vs. Displacement

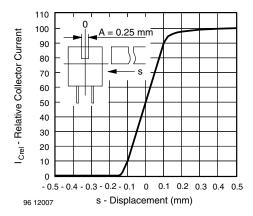
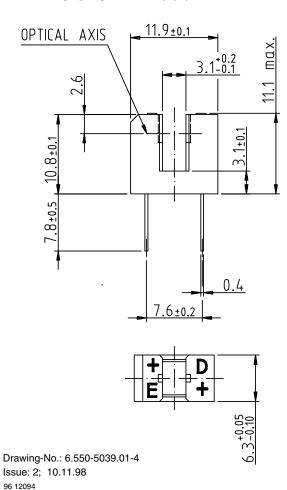
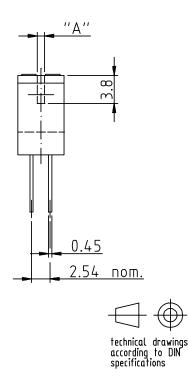


Fig. 13 - Relative Collector Current vs. Displacement

#### **PACKAGE DIMENSIONS** in millimeters





weight: ca. 0.80g

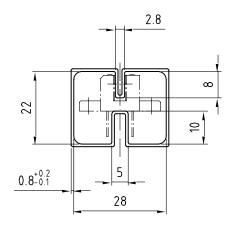
## TCST1103, TCST1202, TCST1300

Vishay Semiconductors

# Transmissive Optical Sensor with Phototransistor Output



#### **TUBE DIMENSIONS** in millimeters



With rubber stopper Tolerance: ±0.5mm Length: 575±1mm

Drawing-No.: 9.700-5100.01-4

Issue: 1; 25.02.00

20252



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